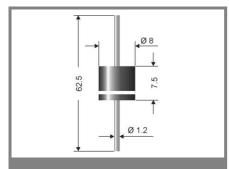
## P 600 A...P 600 S



### **Axial lead diode**

# Standard silicon rectifier diodes

P 600 A...P 600 S

**Forward Current: 6 A** 

Reverse Voltage: 50 to 1200 V

#### **Features**

• Max. solder temperature: 260°C

 Plastic material has UL classification 94V-0

#### **Mechanical Data**

Plastic case 8 x 7.5 [ mm ] / P-600 Style

• Weight approx.: 1.5 g

 Terminals: plated terminals solderable per MIL-STD-750

. Mounting position: any

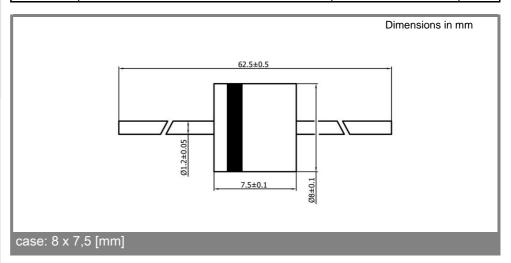
 Standard packaging: 500 pieces per ammo

- 1) Valid, if leads are kept at T<sub>A</sub> at a distance of 10 mm from case
- 2) I<sub>F</sub>= 5A, T<sub>i</sub>=25°C
- 3)  $T_A = 25 \,^{\circ}C$
- 4) Thermal resistance from junction to lead/terminal at a distance 0 mm from case
- 5) Max. junction temperature Tj  $\leq$  200 °C in bypass mode / DC forward mode

Туре	Repetitive peak reverse voltage	Surge peak reverse voltage	Max. reverse recovery time $I_F = -A$ $I_R = -A$ $I_{RR} = -A$	Max. forward voltage
	V <sub>RRM</sub> V	V <sub>RSM</sub> V	t <sub>rr</sub>	V <sub>F</sub> <sup>2)</sup>
P 600 A	50	50	-	1,0
P 600 B	100	100	-	1,0
P 600 D	200	200	-	1,0
P 600 G	400	400	-	1,0
P 600 J	600	600	-	1,0
P 600 K	800	800	-	1,0
P 600 M	1000	1000	-	1,0
P 600 S	1200	1200	-	1,0

<b>Absolute Maximum Ratings</b> T <sub>A</sub> = 25 °C, unless otherwise specified						
Symbol	Conditions	Values	Units			
$I_{FAV}$	Max. averaged fwd. current, R-load, $T_A = 50$ °C <sup>1)</sup>	6	Α			
I <sub>FRM</sub>	Repetitive peak forward current f > 15 Hz <sup>1)</sup>	60	Α			
I <sub>FSM</sub>	Peak forward surge current 50 Hz half sinus-wave 3)	400	Α			
i²t	Rating for fusing, t < 10 ms <sup>3)</sup>	800	A²s			
R <sub>thA</sub>	Max. thermal resistance junction to ambient 1)		K/W			
R <sub>thL</sub>	Max. thermal resistance junction to terminals <sup>4)</sup>	5,5	K/W			
T <sub>j</sub>	Operating junction temperature	-50+175 ( $T_j \le 200$ °C in bypass mode <sup>5)</sup> )	°C			
T <sub>s</sub>	Storage temperature	-50+175	°C			

Characte	Characteristics T <sub>A</sub> = 25 °C, unless otherwise spe		ecified
Symbol	Conditions	Values	Units
$I_R$	Maximum leakage current, $T_j = 25 ^{\circ}\text{C}$ ; $V_R = V_{RRM}$	<25	μΑ
	$T_j = {^{\circ}C}; V_R = V_{RRM}$		
CJ	Typical junction capacitance (at MHz and applied reverse voltage of V)	-	pF
Q <sub>rr</sub>	Reverse recovery charge (U <sub>R</sub> = V; I <sub>F</sub> = A; dI <sub>F</sub> /dt = A/ms)	-	μC
E <sub>RSM</sub>	Non repetitive peak reverse avalanche energy $(I_R = mA; T_j = {^{\circ}C}; inductive load switched off)$	-	mJ



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